

View Online at <https://aerobasegroup.com/nsn/5961-01-381-1363>

Inclosure Material:

Glass all semiconductor device diode

Overall Length:

0.150 inches all semiconductor device diode and 0.170 inches all semiconductor device diode

Terminal Length:

1.000 inches all semiconductor device diode

Overall Diameter:

0.068 inches all semiconductor device diode and 0.076 inches all semiconductor device diode

Component Function Relationship:

Matched

Component Name And Quantity:

2 semiconductor device diode

Mounting Method:

Terminal all semiconductor device diode

Field Force Effect Type:

Electrostatic charge

Semiconductor Material:

Silicon all semiconductor device diode

Voltage Rating In Volts Per Characteristic:

8.0 breakdown voltage, instantaneous all semiconductor device diode

Power Rating Per Characteristic:

150.0 milliwatts small-signal input power, common-collector absolute all semiconductor device diode

Maximum Operating Temperature Per Measurement Point:

150.0 degrees celsius ambient air all semiconductor device diode

Test Data Document:

13499-580-6557-001 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

2 uninsulated wire lead all semiconductor device diode

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

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